Liquid Crystalline Polymers for Efficient Bilayer-Bulk-Heterojunction Solar Cells

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The unique temperature-dependent solubility of liquid crystalline poly(2,5-bis(3-alkylthiophen-2-yl)thieno[3,2-b]thiophene) (PBTTT) enabled us to construct the first bilayer-bulk-heterojunction devices based on a PBTTT:PCBM (1:2)/MDMO-PPV:[70]PCBM (1:4) active layer. The bilayer device exhibited an extended optical absorption over the solar spectrum and concentration gradient that enhanced charge carrier transport. Postannealing the bilayer-bulk-heterojunction devices yielded a Voc of 0.59 V, Jsc values of 10.1–10.7 mA/cm², an FF of 0.50, and PCE values of 3.0–3.2%, showing an increased Jsc and PCE by a factor of 2 with respect to their single layer counterparts. This study suggests that the bilayered device structure has distinct advantages for the development of highly efficient polymer solar cells.

1. Introduction

The increasing demands for inexpensive renewable energy sources have stimulated extensive research activities to develop low-cost and highly efficient photovoltaic devices, particularly polymer solar cells.1–3 The photovoltaic effect in a polymer solar cell involves the generation of electron–hole pairs (i.e., excitons) in the donor (polymer) phase under illumination, followed by subsequent charge separation and collection at opposite electrodes. Dissociation of the excitons (i.e., charge separation) occurs only at the heterojunction interface between semiconducting materials of different ionization potentials or electron affinities. Bulk-heterojunction solar cells with the polymer donor and acceptor mixing at the molecular level to maximize the interfacial area for charge separation have thus been considered to be ideal photovoltaic devices.4 Typical donor-type polymers include derivatives of poly(p-phenylene vinylene) and polythiophene, such as poly[2-methoxy-5-(3,7-dimethyloctyloxy)-1,4-phenylenevinylene] (MDMO-PPV)5 and regioregular poly(3-hexylthiophene) (P3HT).6–9 while a soluble C60 derivative (i.e., 1-(3-methoxy carbonyl)propyl-1-phenyl[6,6]C61, PCBM) has been widely used as the acceptor.9

In a bulk-heterojunction, the efficiency of charge transfer from donor to acceptor can be unity as the donor–acceptor are often phase separated at the length scale within the exciton diffusion length (10–20 nm).1,4 Therefore, it is of paramount importance to increase the exciton creation. For this purpose, many innovative synthetic routes have been devised to produce various low band gap polymers, such as donor–π-acceptor conjugated polymers10,11 and polythiophenes grafted with appropriate side chains12 or copolymerized with fluorene moieties,13 for harvesting solar photons. Recent studies have shown that the hole transport is also important to highly efficient bulk-heterojunction polymer solar cells. For instance, the higher hole mobility of 0.05–0.1 cm²/V s for P3HT14,15 than that for MDMO-PPV (∼10⁻⁴ cm²/V s)16 has led to the higher reported power conversion efficiency (PCE, up to 5%)9 for the former than that for the latter (PCE = 2.5%)9 in their bulk-heterojunction solar cells with PCBM as the electron donor. The high efficiency of P3HT-based solar cells arises from the postannealing-induced formation of a microcrystalline lamellar stacking of P3HT in the solid state17,18 to facilitate hole transport and reduce charge recombination. MDMO-PPV and P3HT are amorphous and semicrystalline, respectively, both exhibiting a significant amount of kinetically trapped disorders in the solid state film. It is necessary to increase the mesoscopic order and crystallinity for these polymers in order to enhance the efficiency of charge carrier transport. In this context, a new class of polythiophene derivatives, including poly(2,5-bis(3-alkylthiophen-2-yl)thieno[3,2-b]thiophene) (PBTTT),19 has recently been synthesized to contain chemical moieties with strong π–π intermolecular interactions for close packing of the macromolecule chains into large crystalline domains upon crystallization from a liquid-crystal phase.20–22 Due to the increased structure order and crystallinity, thin-film transistors made from PBTTT have been demonstrated to exhibit a hole mobility of 0.2–0.6 cm²/V s,23–26 which is higher than that of P3HT and is compared favorably to that of amorphous silicon. However, the use of such a high-mobility semiconducting polymer in bulk-heterojunction solar cells, though very promising, hardly has been investigated while its use in a single-layer bulk-heterojunction solar cell was briefly discussed in a recent paper.27 Here, we report our study on bilayer-bulk-heterojunction solar cells, involving a PBTTT/PCBM active layer. The use of the bilayer structure is to introduce the concentration gradient of charge carriers to reduce the loss by recombination as charge carrier transport is a competitive process with charge recombination in a polymer bulk-heterojunction solar cell. The bilayer structure can also enhance light harvesting by covering the optical absorption for each of the constituent layers. Although concentration gradients can be created in bilayer and even multilayer devices by selective evaporation,28–30 it is not always easy to prepare polymer solar cells with a multilayer structure by solution-casting due to solubility mismatching.

PBTTT liquid crystalline polymers exhibit an interesting solubility in 1,2-dichlorobenzene (DCB) or chlorobenzene (CB)–high solubility at a relatively high temperature but insoluble at room temperature. This unique temperature-dependent solubility of PBTTT enabled us to spin-coat a DCB solution of PBTTT at 70 °C and another overlaid polymer (e.g.,
MDMO-PPV) from the same solvent at room temperature without dissolving the preformed underlying PBTTT layer. As a result, the fabrication of single-layer and bilayer-bulk-heterojunction solar cells from the PBTTT of a high hole mobility by an all-solution process was achieved. Large crystalline domains formed even within a PBTTT:PCBM blend upon postannealing. Solar cells with a PBTTT:PCBM (1:2 w/w) MDMO-PPV:[70]PCBM (1:4 w/w) bilayer structure showed remarkably enhanced solar absorption and charge transport efficiencies. Both the short circuit current ($J_{sc}$) and PCE of the bilayer solar cells were found to increase by a factor of up to about two with respect to their single-layer counterparts, indicating that the bilayer structure has a distinct advantage.

2. Experimental Sections

Materials. Indium–tin oxide (ITO) glass was purchased from Delta Technologies Limited while PEDOT:PSS (Baytron P AI4083) was obtained from Bayer Inc. PBTTT and P3HT were purchased from EMD Chemicals (Merck), Inc., and Rieke Metals, Inc., respectively. [60]PCBM was supplied by NanoC, Inc. MDMO-PPV, and [70]PCBM and Al (99.999%) were purchased from Aldrich Chemicals, Inc. The TiO$_2$ precursor solution was prepared according to the published procedure, and was diluted by 1:10 in ethanol for spin-coating.

Characterizations. UV/visible absorption of dilute solutions (0.1 mg/mL) and thin films (~100 nm) of PBTTT, P3HT, and MDMO-PPV was measured on a PerkinElmer Lambda 900 UV/vis/NIR spectrometer. The cyclic voltammetry was performed on a CH 760 potentiostat, in an acetonitrile solution of 0.1 mol/L of [Bu$_4$N]PF$_6$ at a potential sweep rate of 0.05 V/s at room temperature. The current voltage ($V-J$) curves were recorded on a Keithly 2400 multimeter. Postannealing of some devices was conducted by heating at 120 °C for 4 min, followed by cooling to room temperature at a cooling speed of 1 deg/min.

The current–voltage ($I-V$) curves were recorded on a Keithly 2400 source-measurement unit. The photocurrent was measured under simulated AM1.5G irradiation (100 mW/cm$^2$), using a xenon lamp-based solar simulator (XPS-400, Solar Light Co.). The fill factor (FF) was calculated by FF = $(V_{oc} J_{max})/(J_{sc} V_{oc})$, where $V_{max}$ and $J_{max}$ are the voltage and the current density in the maximum power point of the $I-V$ curve in the fourth quadrant. The normal power conversion efficiency was calculated from the expression

$$PCE = FF \times I_{sc} (mA/cm^2) \times V_{oc}(V)/P_{in} (mW/cm^2)$$

where $V_{oc}$, $I_{sc}$, FF, and $P_{in}$ are the open circuit voltage, short circuit current, fill factor, and incident light power, respectively. All devices were fabricated and tested in oxygen and moisture-free nitrogen environment inside a glovebox (~0.3 ppm O$_2$ and H$_2$O).

3. Results and Discussion

The molecular structure of the particular PBTTT sample used in this study is given in the inset of Figure 1a. As can be seen, each monomer unit comprises two thiophene rings and one fused ring with two alkyl side chains (R = C$_2$H$_5$) attached onto the neighboring thiophene rings in a tail-to-tail configuration. The rotational invariance of the two symmetrically fused thiophene rings in the polymer backbone facilitates the adoption of a low-energy backbone conformation favorable for the formation of highly ordered crystalline domains. On the other hand, the tail-to-tail arrangement of the alkyl side chains can promote self-organization and minimize steric interactions, if any, between the neighboring alkyl groups for a backbone planarity. These structural features make PBTTT attractive for high-efficiency solar cell applications.

Figure 1a shows the UV–visible absorption of the solution-cast thin films (~60 nm) of MDMO-PPV, P3HT, and PBTTT, respectively. Also included is the corresponding PBTTT film...
thienothiophene aromatic rings in the PBTTT backbone. In solution due to the presence of the highly delocalized absorption maximum (and onset) for PBTTT compared to P3HT (Figure 1b). There is an about 20 nm red-shift in the solution absorption of the two polymers in dilute solutions (see the inset of corresponding optical energy gaps estimated from the onset PBTTT (2.1 eV) and P3HT (2.2 eV) are consistent with the spectroscopic differences clearly indicate an enhanced absorption to the solar spectrum for PBTTT, since the maximum photon flux of the solar spectrum is at ~700 nm (1.8 eV).

Electrochemical cyclic voltammetry was performed to determine the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) levels of PBTTT. Figure 1b shows a cyclic voltammogram of a PBTTT thin film. For comparison, the corresponding cyclic voltammogram of P3HT is also given in Figure 1b. Reversible oxidation and reduction processes were observed for both PBTTT and P3HT, which are typical for polythiophene derivatives. The onset potential for oxidations ($E_{ox}$) of both PBTTT and P3HT is ca. 0.72 V vs. Ag wire while the onset potential for reduction ($E_{red}$) of PBTTT is ca. −1.44 V vs. Ag wire that is ~0.1 eV higher than that of P3HT. The HOMOs of PBTTT and P3HT are then calculated to be −5.1 eV, and the LUMOs of PBTTT and P3HT are −3.0 and −2.9 eV, respectively. The electrochemically determined band gaps for PBTTT (2.1 eV) and P3HT (2.2 eV) are consistent with the corresponding optical energy gaps estimated from the onset absorption of the two polymers in dilute solutions (see the inset of Figure 1b). There is an about 20 nm red-shift in the solution absorption maximum (and onset) for PBTTT compared to P3HT in solution due to the presence of the highly delocalized thienothiophene aromatic rings in the PBTTT backbone.

Figure 2a shows a schematic representation of a single-layer bulk-heterojunction solar cell based on a blend film of PBTTT:

PCBM (1:3 w/w). A spin-coated poly(3,4-ethylenedioxythiophene):poly(styrene sulfonate) (PEDOT:PSS) thin film on the top of the ITO substrate acts as a buffer layer. The PBTTT/PCBM blend film was prepared by spin-coating a mixture of codissolved PBTTT (20 mg) and PCBM (60 mg) in 1 mL of DCB at 70 °C on the top surface of the ITO/PEDOT layer, followed by annealing at 80 °C for 30 min. The energy-level diagram for the materials involved in the single-layer photovoltaic device is also given in Figure 2a. Since the HOMO and LUMO of PBTTT are 1.0 and 0.7 eV higher than the corresponding energy levels of PCBM, PBTTT and PCBM act as a donor and an acceptor, respectively. The HOMO and LUMO of PBTTT match well with work functions of the anode and cathode, respectively, for both the hole and electron conduction.

In view of the importance of the interface morphology to thin film devices, including field effect transistors (FETs)) and solar cells, we investigated temperature effects on the performance for solar cells prepared by spin-casting PBTTT/PCBM (1:3 w/w) onto the ITO/PEDOT substrates at different temperatures over 20–70 °C. Current density–voltage ($J–V$) characteristics at different temperatures are shown in Figure 2b, along with the corresponding temperature-dependent PEC curve (inset of Figure 2b). As can be seen, the substrate temperature affected mainly the short circuit current density ($J_{sc}$) with a peak at ~550 nm (2.3 eV). Compared to those of MDMO-PPV (~440 nm) and P3HT (~500 nm), the maximum absorption of PBTTT is approximately 110 and 50 nm red-shifted, respectively. These spectroscopic differences clearly indicate an enhanced absorption to the solar spectrum for PBTTT, since the maximum photon flux of the solar spectrum is at ~700 nm (1.8 eV).
and pinhole free surface (the rms roughness is less than 1 nm). The decreased PCE observed at a PBTTT:PCBM weight ratio of 1:4 is, most probably, due to the over suppressed hole transport induced by the relatively reduced nanoscale clusters of PBTTT in the active layer and/or increased PCBM trap sites for charge combination. The diluted solar absorption associated with the relatively reduced amount of PBTTT in the active layer may also contribute to the reduced PCE to a certain extent. Consequently, the 1:3 weight ratio for PBTTT to PCBM was chosen as the optimized value for subsequent investigations in this study.

To further enhance the device performance, we performed the postannealing study. Previous work has demonstrated that the thermal annealing liquid crystalline mesophase of pure PBTTT can increase the size of crystalline domains in the polymer film to facilitate the hole transport. Figure 3a reproduces the differential scanning calorimetry (DSC) curves for PBTTT, which shows two discrete endotherms upon heating with the transition from a crystal phase below \( 100 \, ^\circ\text{C} \) to a liquid phase above \( 150 \, ^\circ\text{C} \), through the liquid-crystal (LC) phase over about 100–140 °C. The AFM image given in Figure 3b reveals that annealing a thin film of PBTTT:PCBM (1:3 w/w, 150 nm) on the top of an ITO/PEDOT substrate up to above 120 °C caused the morphology change from a module-like nanostructure characteristic of the as-cast PBTTT film (cf. Figure 2d) to an oriented polycrystalline microstructure, which is rather unique among the semiconducting polymers. The large size of PBTTT crystalline domains (ca. submicrons) thus formed are assembled with several smaller sized crystalline domains of reoriented PBTTT chains in the LC phase upon crystallization. Compared with the as-cast PBTTT film, an about 20-nm red-shift was observed for the thermally annealed PBTTT film with crystalline domains (cf. Figure 1a).

Figure 3c shows the \( J\!-\!V \) curves for the PBTTT:PCBM solar cells before and after being annealed at \( 80 \, ^\circ\text{C} \) for 30 min. The

\( V_{oc} \) of the ITO/PEDOT/PBTTT:PCBM (1:3)/Al solar cell remained unchanged while its \( J_{sc} \) slightly increased and the FF significantly increased from 0.36 to 0.55 upon postannealing (vide supra). As a result, the PCE increased from 1.5% (vide supra) to 2.3%. In a polymer solar cell, the FF is determined by the product of the charge carrier lifetime \( \tau \) times the mobility \( \mu \). Therefore, the improved \( J_{sc} \) and FF indicate an enhanced charge carrier transport, attributable to the formation of large PBTTT crystalline domains in the active layer induced by thermal annealing. Given that PBTTT dominates the crystalline domains while PCBM forms mainly the disordered domains for electron transport in the bulk-heterojunction, the postannealing should reduce the free volume and the density of defects at the interface and in the bulk volume of PBTTT to facilitate the hole transport.

In addition to the enhanced hole transport described above, it is essential to also improve the electron transport in order to optimize the device performance. In this context, the incorporation of a thin film of TiO\(_2\) between the active layer and the Al electrode has been demonstrated to significantly improve the photovoltaic outputs of P3HT:PCBM devices. This is because TiO\(_2\) is a good electron transporting material, with its LUMO (−4.4 eV) lower than that of PCBM (−3.7 eV), and is very close to the work function of Al (−4.3 eV) (inset of Figure 3c). As such, we have also incorporated a thin TiO\(_2\) layer into our PBTTT:PCBM devices. Owing to the enhanced electron transport associated with TiO\(_2\), the as-prepared ITO/PEDOT/PBTTT:PCBM (1:3 w/w)/TiO\(_2\)/Al device showed a relatively good performance with respect to its counterpart without TiO\(_2\), exhibiting a \( V_{oc} \) of 0.55 V, a \( J_{sc} \) of 9.3 mA/cm\(^2\), a FF of 0.41, and a PCE of 2.1% (Figure 3c). Subsequent postannealing led to further enhanced performance with a \( V_{oc} \) of 0.57 V, \( J_{sc} \) of 9.9 mA/cm\(^2\), FF of 0.47, and PCE of 2.6% due, once again, to the formation of polycrystalline domains in the active layer.

![Figure 3](image_url)

**Figure 3.** (a) Differential scanning calorimetry of PBTTT at a heating rate of 10 deg/min under N\(_2\) atmosphere. (b) An AFM phase image of a PBTTT:PCBM (1:3 wt %) blend film after being annealed at 120 °C for 4 min, followed by cooling to room temperature at a cooling speed of 1 deg/min. (c) \( J\!-\!V \) characteristics of the as-prepared and postannealed PBTTT:PCBM (1:3 wt %) solar cells with and without TiO\(_2\). The insets show a schematic device configuration (left) of the PBTTT:PCBM (1:3 wt %) solar cell with TiO\(_2\), and the associated energy level diagram (right).

![Figure 4](image_url)

**Figure 4.** (a) Optical absorption spectra for the blend films of PBTTT:PCBM (1:2 wt %) and MDMO-PPV:[70]PCBM (1:4 wt %) and the bilayer blend film of PBTTT:PCBM (1:2 wt %)/MDMO-PPV:[70]PCBM (1:4 wt %). The insets show the digital photographs of PBTTT in CB at 70 °C (up) and PBTTT and MDMO-PPV in CB at room temperature (bottom). (b) Schematic device configurations (up) of the bilayer-bulk-heterojunction solar cell with and without TiO\(_2\), and the associated energy level diagram (bottom). (c) \( J\!-\!V \) characteristics of the single-layer and bilayer bulk-heterojunction solar cells based on PBTTT:PCBM (1:2 wt %) and MDMO-PPV:[70]PCBM (1:4 wt %) with and without TiO\(_2\) before and after postannealing.
As mentioned earlier, the unique temperature-dependent solubility of PBTTT (cf. Figure 4) could enable us to fabricate bilayer solar cells with enhanced solar absorption and concentration gradients for minimizing the charge recombination. Figure 4a shows the UV/vis absorption of single-layer films of PBTTT:PCBM, MDMO-PPV:[70]PCBM, and a bilayer film of PBTTT:PCBM (1:2)/MDMO-PPV:[70]PCBM (1:4), respectively. Due to the dilute effect associated with the high content of PCBM or [70]PCBM in the polymer layers, PBTTT only absorbs solar photons in the range of ca. 500–650 nm (red curve of Figure 4a) while MDMO-PPV absorbs the solar photons over about 400–500 nm only (yellow curve of Figure 4a, cf. Figure 1a). The bilayer blend film, however, showed a continuous solar absorption spectrum from 400 to 650 nm (black curve of Figure 4a), arising from both polymers with additional absorption extended further over ca. 720 nm associated to [70]PCBM. As is schematically shown in Figure 4b, bilayer-bulk-heterojunction solar cells were thus fabricated from these bilayer blend films with and without TiO₂. In view of the red-shifted absorption of PBTTT with respect to MDMO-PPV, the thickness of the first layer (i.e., the PBTTT layer) was controlled to be thin (∼60 nm) to allow the incident light to reach the second layer. As the HOMO of PBTTT is 0.2 eV higher than that of MDMO-PPV, holes from the second layer can effectively pass through the first layer to the anode. The donor–acceptor weight ratio is controlled to be 1:2 in the first layer and 1:4 in the second layer to reduce the optical absorption in the first layer and to create the concentration gradient for minimizing charge recombination.

$J-V$ characteristics of the bilayer-bulk-heterojunction devices are shown in Figure 4c while the numerical photovoltaic parameters are listed in Table 1. Single-layer devices with PBTTT:PCBM and MDMO-PPV:[70]PCBM are also prepared under the identical conditions for references. While both the single PBTTT:PCBM layer and bilayer solar cells exhibited a similar $V_{oc}$ as the as-prepared bilayer device showed a much higher $J_{sc}$ and PCE. It was further found that the $V_{oc}$ is closely related to the relative thickness of the constituent layers in the bilayer bulk-heterojunction. Reducing the thickness of the first layer gradually shifted the $V_{oc}$ of the bilayer solar cell to that of the MDMO-PPV:[70]PCBM device. Typically, the $J_{sc}$ is determined by the product of the photoinjected charge carrier density and the charge carrier mobility; $J_{sc} = n e E$, where $n$ is the charge carrier density, $e$ is the elementary charge, $\mu$ is the mobility, and $E$ is the electric field. The observed high $J_{sc}$ for the bilayer bulk-heterojunction structure is attributable to the increased $n$ by the extended absorption to solar photons as well as the increased $E$ induced by additional electrical forces related to the concentration gradient of charge carriers across the bilayer bulk-heterojunction. The introduction of an additional TiO₂ layer between the active layer and the Al cathode further increased the $J_{sc}$ and PCE for the bilayer bulk-heterojunction device. The formation of large polycrystalline domains of PBTTT in the first layer induced by postannealing also increased the photovoltaic outputs for both devices with and without TiO₂ (Table 1).

4. Conclusions

In summary, we have fabricated highly-efficient bilayer bulk-heterojunction solar cells from high-hole-mobility liquid crystalline polymer (PBTTT). The bilayer structure was demonstrated to show extended optical absorption. Hole transport was enhanced by thermal annealing to form well-ordered large crystalline domains of PBTTT in the PBTTT:PCBM blend film. The temperature-dependent solubility of PBTTT enabled us to construct the first bilayer bulk-heterojunction devices based on a PBTTT:PCBM (1:2)/MDMO-PPV:[70]PCBM (1:4) active layer. The bilayer device exhibited an extended optical absorption over the solar spectrum. Postannealing the bilayer bulk-heterojunction devices yielded a $V_{oc}$ of 0.59 V, $J_{sc}$ values of 10.1–10.7 mA/cm², FF of 0.50, and PCE values of 3.0–3.2%, showing an increased $J_{sc}$ and PCE by a factor of 2 with respect to their single-layer counterparts (cf. Table 1). It is envisioned that further enhanced photovoltaic performance for the PBTTT solar cells could be achieved by surface functionalization during the device preparation to improve the crystallization of PBTTT as the mobility of PBTTT has been demonstrated to strongly depend on the surface chemistry of the substrate. 24

Acknowledgment

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References and Notes


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TABLE 1: Photovoltaic Properties of the Single-Layer and Bilayer Bulk-Heterojunction Solar Cells Based on PBTTT:PCBM (1:2 wt %) and MDMO-PPV:[70]PCBM (1:4 wt %) with and without TiO², before and after Postannealing

<table>
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<th>compositions of active layer</th>
<th>$V_{oc}$ (V)</th>
<th>$J_{sc}$ (mA/cm²)</th>
<th>FF</th>
<th>PCE (%)</th>
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<tr>
<td>PBTTT:PCBM (1:2 wt %)</td>
<td>0.57</td>
<td>5.1</td>
<td>0.40</td>
<td>1.2</td>
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<tr>
<td>MDMO-PPV:[70]PCBM (1:4 wt %)</td>
<td>0.73</td>
<td>5.2</td>
<td>0.49</td>
<td>1.9</td>
</tr>
<tr>
<td>PBTTT:PCBM (1:2 wt %)/MDMO-PPV:[70]PCBM (1:4 wt %)</td>
<td>0.57</td>
<td>9.1</td>
<td>0.41</td>
<td>2.1</td>
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<tr>
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<td>0.59</td>
<td>10.1</td>
<td>0.50</td>
<td>3.0</td>
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<tr>
<td>PBTTT:PCBM (1:2)/MDMO-PPV:[70]PCBM (1:4)/TiO₂</td>
<td>0.57</td>
<td>9.8</td>
<td>0.42</td>
<td>2.4</td>
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<tr>
<td>PBTTT:PCBM (1:2)/MDMO-PPV:[70]PCBM (1:4)/TiO₂-annealed</td>
<td>0.59</td>
<td>10.7</td>
<td>0.50</td>
<td>3.2</td>
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In summary, we have fabricated highly-efficient bilayer bulk-heterojunction solar cells from high-hole-mobility liquid crystalline polymer (PBTTT). The bilayer structure was demonstrated to show extended optical absorption. Hole transport was enhanced by thermal annealing to form well-ordered large crystalline domains of PBTTT in the PBTTT:PCBM blend film. The temperature-dependent solubility of PBTTT enabled us to construct the first bilayer bulk-heterojunction devices based on a PBTTT:PCBM (1:2)/MDMO-PPV:[70]PCBM (1:4) active layer. The bilayer device exhibited an extended optical absorption over the solar spectrum. Postannealing the bilayer bulk-heterojunction devices yielded a $V_{oc}$ of 0.59 V, $J_{sc}$ values of 10.1–10.7 mA/cm², FF of 0.50, and PCE values of 3.0–3.2%, showing an increased $J_{sc}$ and PCE by a factor of 2 with respect to their single-layer counterparts (cf. Table 1). It is envisioned that further enhanced photovoltaic performance for the PBTTT solar cells could be achieved by surface functionalization during the device preparation to improve the crystallization of PBTTT as the mobility of PBTTT has been demonstrated to strongly depend on the surface chemistry of the substrate.


(30) Li, Y.; Cao, Y.; Gao, J.; Wang, D. L.; Yu, G.; Heeger, A. J. Synth. Met. 1999, 99, 243. According to the equations HOMO = -(E_mm + 4.39) eV and LUMO = -(E_mm + 4.39) eV, by assuming that the formal potential of Fc/Fc+ corresponds to a vacuum energy level of ~4.8 eV.


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